EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	14755	(tab near9 (chip or device or circuit)) and (seal$4 or encapsula$4) same (chip or device or circuit)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/18 13:23
S2	6014	(tab near9 semiconductor)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/12/02 10:09
S3	2071	(tab near9 semiconductor) same mount$4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/12/02 10:12
S4	633	(tab near9 semiconductor) same mount$4 and ((seal$4 or encapsl$8) near9 chip)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/12/02 10:25
S5	451	(tab near9 semiconductor) same mount$4 and ((seal$4 or encapsl$8) near9 chip) and (lead$4 near9 mount $4)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/12/02 10:31
S6	86	(tab near9 semiconductor) same mount$4 and ((seal$4 or encapsl$8) near9 chip) and (lead$4 near9 mount $4) and wir$4 and QFN	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/12/02 10:38
S7	80	(tab near9 semiconductor) same mount$4 and ((seal$4 or encapsl$8) near9 chip) and (lead$4 near9 mount $4) and wir$4 and QFN and electrode	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/12/02 11:11
S8	9	(tab near9 semiconductor) same mount$4 and ((seal$4 or encapsl$8) near9 chip) and (lead$4 near9 mount $4) and wir$4 and QFN and electrode and notch	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/12/02 11:12

S9	54	(tab near9 semiconductor) same mount$4 and ((seal$4 or encapsul$8) near9 chip) and (lead$4 near9 mount $4) and wir$4 and QFN and electrode and (notch or slit or deform$8)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/12/02 11:59
S10	7	(tab near9 semiconductor) same mount$4 and ((seal$4 or encapsul$8) near9 chip) and (lead$4 near9 mount $4) and wir$4 and QFN and electrode and (notch or slit or deform$8) and (257/678.ccls.)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/12/02 12:07
S11	9	(tab near9 semiconductor) same mount$4 and ((seal$4 or encapsul$8) near9 chip) and (lead$4 near9 mount $4) and wir$4 and QFN and electrode and (notch or slit or deform$8).clm.	US-PGPUB	OR	ON	2008/12/02 12:08
S12	17	(tab near9 semiconductor) same mount$4 and ((seal$4 or encapsul$8) near9 chip) and (lead$4 near9 mount $4) and wir$4 and QFN and electrode and (notch or slit or deform$8) and (438/106,112,123,126,127.ccls.)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/12/02 12:57

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